

RLSD32A031~241LC/V Series

ULTRA LOW CAPACITANCE TVS/ESD ARRAY

Description

The RLSD32AXX1LC and RLSD32AXX1LV Series are ultra low capacitance transient voltage suppressor arrays, designed to protect applications such as portable electronics and SMART phones. This series is available in both unidirectional and bidirectional configurations and is rated at 350 Watts for an 8/20µs waveshape. The RLSD32AXX1LC and RLSD32AXX1LV Series meets IEC 61000-4-2 (ESD) and IEC 61000-4-4 (EFT) requirements. At higher operating frequencies or faster edge rates, insertion loss and signal integrity are a major concern. This series offers a ultra low capacitance and low leakage current in a miniature SOD-323 package.

Features

- 350 Watts peak pulse power (tp = 8/20µs)
- Transient protection for data lines to IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact) IEC 61000-4-4 (EFT) 40A (5/50ns) IEC 61000-4-5 (Lightning) 24A (8/20µs)
- Small package for use in portable electronics
- Suitable replacement for MLV's in ESD protection applications
- · Protects one I/O or power line
- · Low clamping voltage
- Working voltages: 3.3V, 5V, 12V, 15V, 24V
- Low leakage current
- · Solid-state silicon avalanche technology

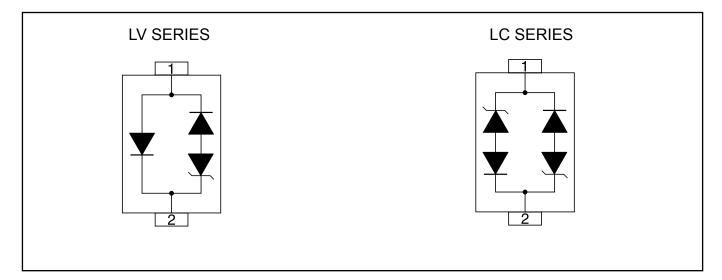
Mechanical Characteristics

- Molded JEDEC SOD-323
- Weight 10 milligrams (Approximate)
- Flammability rating UL 94V-0
- 8mm Tape and Reel Per EIA Standard 481
- Device Marking: Marking Code & Polarity Band (Unidirectional Only)

Applications

- Ethernet 10/100/1000 Base T
- Cellular Phones
- Handheld Wireless Systems
- Personal Digital Assistant(PDA)
- PUSB Interface

Schematic & PIN Configuration



Protection Products

Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (tp =8/20µs)	P _{pk}	350	Watts
Lead Soldering Temperature	TL	260 (10 sec.)	°C
Operating Temperature	TJ	-55 to +125	°C
Storage Temperature	T _{STG}	-55 to +150	°C

Electrical Characteristics (T=25°C)

RLSD32A031LC/RLSD32A031LV

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V _{RWM}	-	-	-	3.0	V
Reverse Breakdown Voltage	V _{BR}	I _T =1mA	3.3	-	-	V
Reverse Leakage Current	I _R	V _{RWM} =3V,T=25°C	-	-	5	μA
Clamping Voltage	Vc	I _{PP} =1Α,I _P =8/20μS	-	-	7.0	V
Junction Capacitance	Cj	V _R = 0V, f = 1MHz	-	-	3	pF

RLSD32A051LC/RLSD32A051LV

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V _{RWM}	-	-	-	5.0	V
Reverse Breakdown Voltage	V_{BR}	I _T =1mA	6.1	-	-	V
Reverse Leakage Current	I _R	V _{RWM} =5V,T=25°C	-	-	5	μA
Clamping Voltage	V _C	Ι _{ΡΡ} =1Α,Ι _Ρ =8/20μS	-	-	9.8	V
Junction Capacitance	C _j	V _R = 0V, f = 1MHz	-	-	3	pF

Electrical Characteristics (T=25°C)

RLSD32A121LC/RLSD32A121LV						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V _{RWM}	-	-	-	12	V
Reverse Breakdown Voltage	V_{BR}	I _T =1mA	13.5	-	-	V
Reverse Leakage Current	I _R	V _{RWM} =12V,T=25°C	-	-	2	μA
Clamping Voltage	Vc	Ι _{ΡΡ} =1Α,Ι _Ρ =8/20μS	-	-	19	V
Junction Capacitance	Cj	V _R = 0V, f = 1MHz	-	-	3	pF

RLSD32A151LC/RLSD32A151LV						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V _{RWM}	-	-	-	15	V
Reverse Breakdown Voltage	V_{BR}	I _T =1mA	16.7	-	-	V
Reverse Leakage Current	I _R	V _{RWM} =15V,T=25°C		-	1	μA
Clamping Voltage	V _C	Ι _{ΡΡ} =1Α,Ι _Ρ =8/20μS	-	-	24	V
Junction Capacitance	C _j	V _R = 0V, f = 1MHz	-	-	3	pF

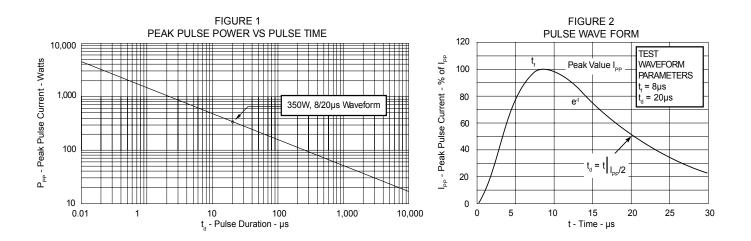
RLSD32A181L	C/RI	SD32A	181LV
RESUSZAIOIE		-30326	

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V _{RWM}	-	-	-	18	V
Reverse Breakdown Voltage	V_{BR}	I _T =1mA	20.0	-	-	V
Reverse Leakage Current	I _R	V _{RWM} =18V,T=25°C	-	-	1	μA
Clamping Voltage	Vc	Ι _{ΡΡ} =1Α,Ι _Ρ =8/20μS	-	-	29	V
Junction Capacitance	C _j	V _R = 0V, f = 1MHz	-	-	3	pF

Electrical Characteristics (T=25°C)

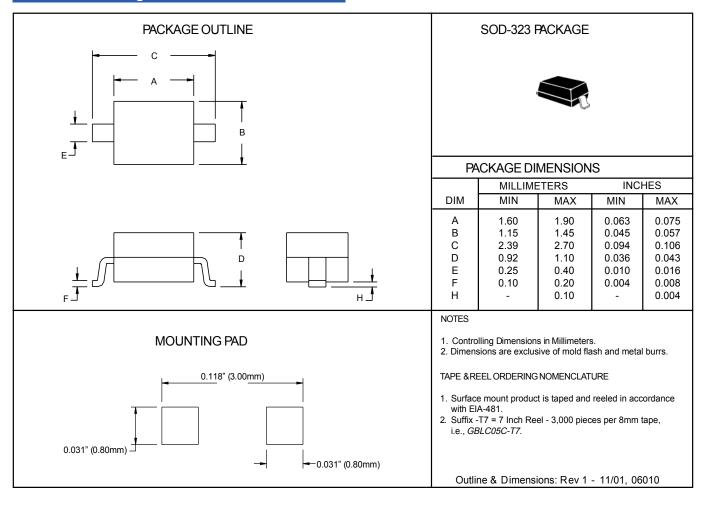
RLSD32A241LC/RLSD32A241LV						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V _{RWM}				24	V
Reverse Breakdown Voltage	V_{BR}	I _T =1mA	26.7			V
Reverse Leakage Current	I _R	V _{RWM} =24V,T=25°C			1	μA
Clamping Voltage	V _C	Ι _{ΡΡ} =1Α,Ι _Ρ =8/20μS			43	V
Junction Capacitance	C _j	V _R = 0V, f = 1MHz			3	pF

Protection Products Typical Characteristics



Protection Products

Outline Drawing - SOD-323



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